BLF6G22-180PN; BLF6G22LS-180PN Power LDMOS transistor

AMPLEON

Rev. 6 — 1 September 2015

Product data sheet

Product profile

1.1 General description

180 W LDMOS power transistor for base station applications at frequencies from 2000 MHz to 2200 MHz.

Table 1. Typical performance

RF performance at $T_{case} = 25$ °C in a common source class-AB production test circuit.

Mode of operation	f	V _{DS}	P _{L(AV)}	Gp	η _D	ACPR
	(MHz)	(V)	(W)	(dB)	(%)	(dBc)
2-carrier W-CDMA	2110 to 2170	32	50	17.5	27.5	-35 ^[1]

^[1] Test signal: 3GPP; test model 1; 64 DPCH; PAR = 7.5 dB at 0.01 % probability on CCDF per carrier; carrier spacing 5 MHz.

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Therefore care should be taken during transport and handling.

1.2 Features and benefits

- Typical 2-carrier W-CDMA performance at frequencies of 2110 MHz and 2170 MHz, a supply voltage of 32 V and an I_{Dq} of 1600 mA:
 - Average output power = 50 W
 - ◆ Power gain = 17.5 dB (typ)
 - ◆ Efficiency = 27.5 %
 - ◆ ACPR = -35 dBc
- Easy power control
- Integrated ESD protection
- Excellent ruggedness
- High efficiency
- Excellent thermal stability
- Designed for broadband operation (2000 MHz to 2200 MHz)
- Internally matched for ease of use
- Qualified up to a supply voltage of 32 V

 Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

■ RF power amplifiers for W-CDMA base stations and multicarrier applications in the 2000 MHz to 2200 MHz frequency range

2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Symbol
BLF6G22-18	80PN (SOT539A)		
1	drain1		
2	drain2	1 2	<u>1</u> ا
3	gate1	5	3
4	gate2	3 4	5
5	source	[1]	4 7
			<u>"</u>
			2 sym117

BLF6G2	22LS-180PN (SOT539B)				
1	drain1				
2	drain2		1 2	1 	
3	gate1		5		
4	gate2		3 4	3	
5	source	[1]		2 sym117	

^[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
BLF6G22-180PN	-	flanged balanced LDMOST ceramic package; 2 mounting holes; 4 leads	SOT539A			
BLF6G22LS-180PN	-	earless flanged balanced LDMOST ceramic package; 4 leads	SOT539B			

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	65	V
V_{GS}	gate-source voltage		-0.5	+13	V
T _{stg}	storage temperature		-65	+150	°C
T _{case}	case temperature		-	150	°C
T _j	junction temperature		-	225	°C

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Туре	Тур	Unit
R _{th(j-case)}	thermal resistance from junction to			0.45	
	case	$P_{L(AV)} = 50 W$	BLF6G22LS-180PN	0.38	K/W

6. Characteristics

Table 6. Characteristics

 T_i = 25 °C per section; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 0.5 \text{ mA}$	65	-	-	V
V _{GS(th)}	gate-source threshold voltage	V_{DS} = 10 V; I_{D} = 144 mA	1.575	1.9	2.3	V
V_{GSq}	gate-source quiescent voltage	V_{DS} = 32 V; I_{D} = 800 mA	1.725	2.1	2.45	V
I _{DSS}	drain leakage current	$V_{GS} = 0 V$				
		V _{DS} = 28 V	-	-	3	μΑ
		V _{DS} = 60 V	-	-	5	μΑ
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	-	25	-	Α
I _{GSS}	gate leakage current	$V_{GS} = 11 \text{ V}; V_{DS} = 0 \text{ V}$	-	-	300	nA
9 _{fs}	forward transconductance	$V_{DS} = 10 \text{ V}; I_D = 7.2 \text{ A}$	-	10	-	S
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 5 \text{ A}$	-	0.1	0.165	Ω

7. Application information

Table 7. Application information

Mode of operation: 2-carrier W-CDMA; PAR 7.5 dB at 0.01 % probability on CCDF; 3GPP test model 1; 1 to 64 PDPCH; f_1 = 2112.5 MHz; f_2 = 2117.5 MHz; f_3 = 2162.5 MHz; f_4 = 2167.5 MHz; RF performance at V_{DS} = 32 V; I_{Dq} = 1600 mA; T_{case} = 25 °C; unless otherwise specified; in a class-AB production test circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	$P_{L(AV)} = 50 W$	16.3	17.5	18.7	dB
RLin	input return loss	$P_{L(AV)} = 50 W$	-	-10	-6.5	dB
η_{D}	drain efficiency	$P_{L(AV)} = 50 \text{ W}$	25	27.5	-	%
ACPR	adjacent channel power ratio	$P_{L(AV)} = 50 W$	-	-35	-33	dBc

Table 8. Application information

Mode of operation: 1-carrier W-CDMA; PAR 7.5 dB at 0.01 % probability on CCDF; 3GPP test model 1; 1 to 64 PDPCH; f_1 = 2162.5 MHz; f_2 = 2167.5 MHz; RF performance at V_{DS} = 32 V; I_{Dg} = 1600 mA; T_{case} = 25 °C; unless otherwise specified; in a class-AB production test circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
PARO	output peak-to-average ratio	P _{L(AV)} = 115 W; at 0.01 % probability on CCDF	4.05	4.5	-	dB

7.1 Ruggedness in class-AB operation

The BLF6G22-180PN and BLF6G22LS-180PN are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: $V_{DS} = 28 \text{ V}$; $I_{Dq} = 1600 \text{ mA}$; $P_L = 180 \text{ W}$ (CW); f = 2170 MHz.

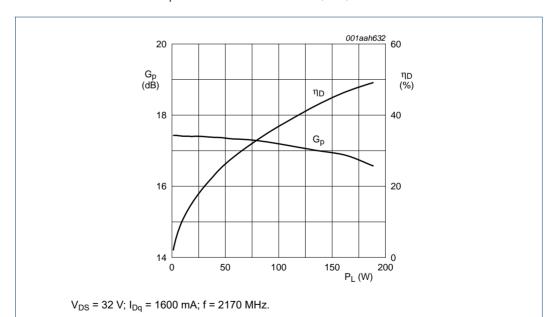
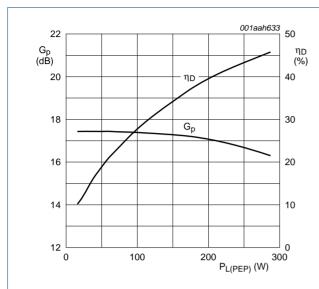


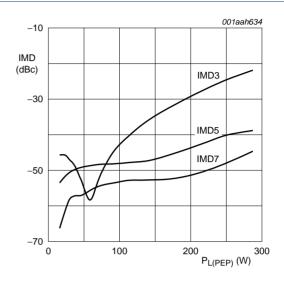
Fig 1. One-tone CW power gain and drain efficiency as functions of load power; typical values

BLF6G22-180PN_22LS-180PN#6



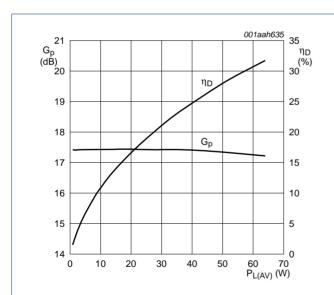
 V_{DS} = 32 V; I_{Dq} = 1600 mA; f_1 = 2170 MHz; f_2 = 2170.1 MHz.

Fig 2. Two-tone CW power gain and drain efficiency as functions of peak envelope load power; typical values



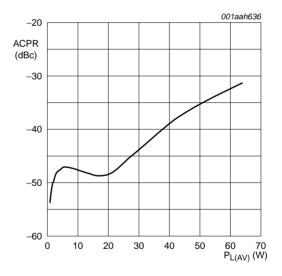
 V_{DS} = 32 V; I_{Dq} = 1600 mA; f_1 = 2170 MHz; f_2 = 2170.1 MHz.

Fig 3. Two-tone intermodulation distortion as a function of peak envelope load power; typical values



 V_{DS} = 32 V; I_{Dq} = 1600 mA; f_1 = 2162.5 MHz; f_2 = 2167.5 MHz; carrier spacing 5 MHz.

Fig 4. 2-carrier W-CDMA power gain and drain efficiency as functions of average load power; typical values

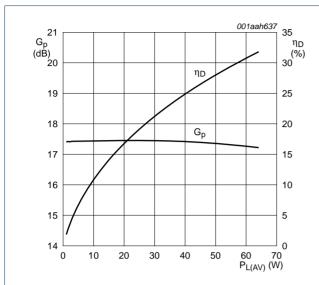


 V_{DS} = 32 V; I_{Dq} = 1600 mA; f_1 = 2162.5 MHz; f_2 = 2167.5 MHz; carrier spacing 5 MHz.

Fig 5. 2-carrier W-CDMA adjacent channel power ratio as function of average load power; typical values

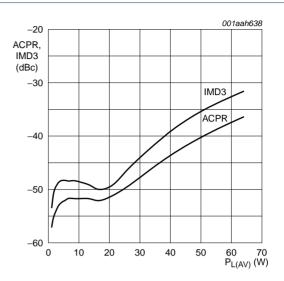
BLF6G22(LS)-180PN

Power LDMOS transistor



 V_{DS} = 32 V; I_{Dq} = 1600 mA; f_1 = 2157.5 MHz; f_2 = 2167.5 MHz; carrier spacing 10 MHz.

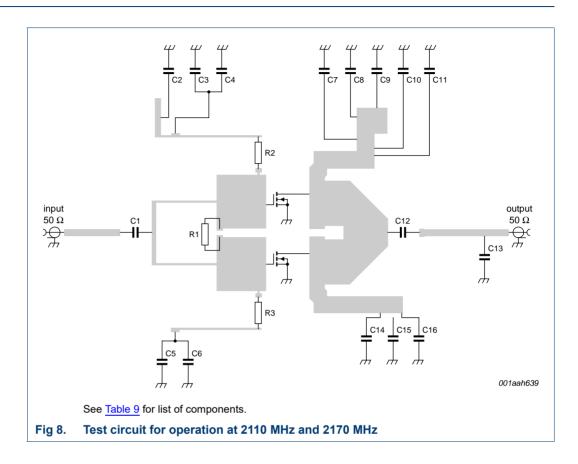
Fig 6. 2-carrier W-CDMA power gain and drain efficiency as functions of average load power; typical values

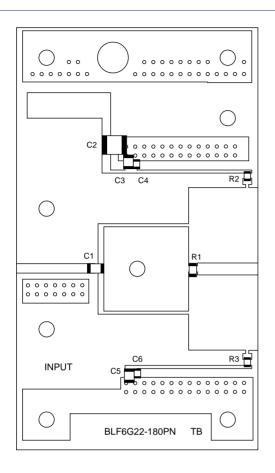


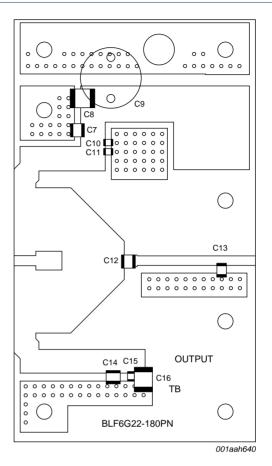
 V_{DS} = 32 V; I_{Dq} = 1600 mA; f_1 = 2157.5 MHz; f_2 = 2167.5 MHz; carrier spacing 10 MHz.

Fig 7. 2-carrier W-CDMA adjacent channel power ratio and third order intermodulation distortion as functions of average load power; typical values

8. Test information







Striplines are on a double copper-clad Rogers R04350 Printed-Circuit Board (PCB) with ε_r = 3.5 and thickness = 0.76 mm. See Table 9 for list of components.

Fig 9. Component layout for 2110 MHz and 2170 MHz test circuit

Table 9. List of components For test circuit, see Figure 8 and Figure 9.

Component	Description	Value	Remarks
C1, C3, C5	ATC multilayer ceramic chip capacitor	10 pF	<u>[1]</u>
C2, C8, C16	TDK multilayer ceramic chip capacitor	4.7 μF	
C4, C6	TDK multilayer ceramic chip capacitor	220 nF	
C7, C14	ATC multilayer ceramic chip capacitor	10 pF	[2]
C9	electrolytic capacitor	220 μF; 63 V	
C10, C11, C15	Murata ceramic chip capacitor	100 nF	
C12	ATC multilayer ceramic chip capacitor	15 pF	[2]
C13	ATC multilayer ceramic chip capacitor	0.3 pF	<u>[1]</u>
R1	chip resistor	33 Ω	
R2, R3	chip resistor	5.6 Ω	

^[1] American technical ceramics type 100B or capacitor of same quality.

BLF6G22-180PN_22LS-180PN#6

All information provided in this document is subject to legal disclaimers.

© Ampleon The Netherlands B.V. 2015. All rights reserved.

^[2] American technical ceramics type 180R or capacitor of same quality.

9. Package outline

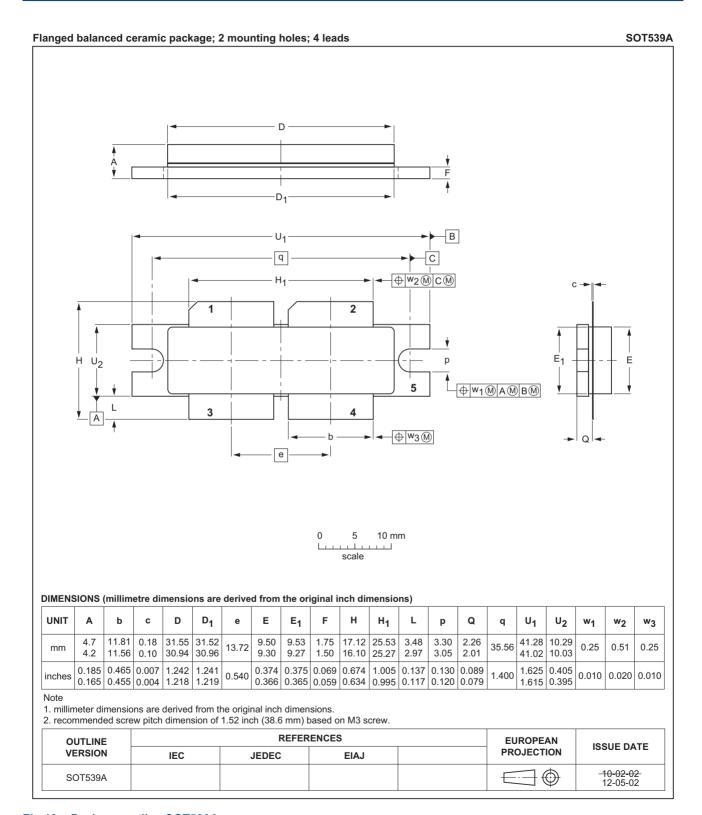


Fig 10. Package outline SOT539A

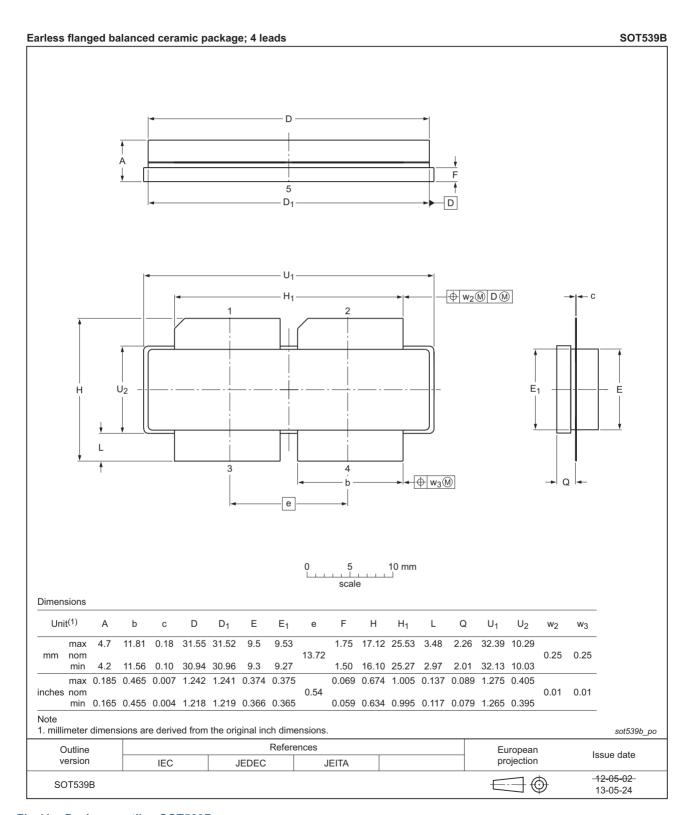


Fig 11. Package outline SOT539B

10. Abbreviations

Table 10. Abbreviations

Acronym	Description
3GPP	3rd Generation Partnership Project
CCDF	Complementary Cumulative Distribution Function
CW	Continuous Wave
DPCH	Dedicated Physical CHannel
IMD	InterModulation Distortion
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
LDMOST	Laterally Diffused Metal-Oxide Semiconductor Transistor
PAR	Peak-to-Average power Ratio
PDPCH	transmission Power of the Dedicated Physical CHannel
RF	Radio Frequency
VSWR	Voltage Standing-Wave Ratio
W-CDMA	Wideband Code Division Multiple Access

11. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLF6G22-180PN_22LS-180PN#6	20150901	Product data sheet	-	BLF6G22-180PN_22LS-180PNV.5
Modifications:	 The format of this document has been redesigned to comply with the new identity guidelines of Ampleon. 			
	• Legal t	texts have been adapted	d to the nev	v company name where appropriate.
BLF6G22-180PN_22LS-180PN V.5	20130712	Product data sheet	-	BLF6G22-180PN_22LS-180PN_4
BLF6G22-180PN_22LS-180PN_4	20100304	Product data sheet	-	BLF6G22-180PN_22LS-180PN_3
BLF6G22-180PN_22LS-180PN_3	20091211	Objective data sheet	-	BLF6G22-180PN_2
BLF6G22-180PN_2	20080423	Product data sheet	-	BLF6G22-180PN_1
BLF6G22-180PN_1	20080221	Preliminary data sheet	-	-

12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.ampleon.com.

12.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Ampleon does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Ampleon sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between Ampleon and its customer, unless Ampleon and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the Ampleon product is deemed to offer functions and qualities beyond those described in the Product data sheet.

12.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, Ampleon does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. Ampleon takes no responsibility for the content in this document if provided by an information source outside of Ampleon.

In no event shall Ampleon be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, Ampleon' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of Ampleon.

Right to make changes — Ampleon reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — Ampleon products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an

Ampleon product can reasonably be expected to result in personal injury, death or severe property or environmental damage. Ampleon and its suppliers accept no liability for inclusion and/or use of Ampleon products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. Ampleon makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using Ampleon products, and Ampleon accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the Ampleon product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

Ampleon does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using Ampleon products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). Ampleon does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — Ampleon products are sold subject to the general terms and conditions of commercial sale, as published at http://www.ampleon.com/terms, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Ampleon hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of Ampleon products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

BLF6G22-180PN 22LS-180PN#6

BLF6G22(LS)-180PN

Power LDMOS transistor

Non-automotive qualified products — Unless this data sheet expressly states that this specific Ampleon product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. Ampleon accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without Ampleon' warranty of the product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond Ampleon' specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies Ampleon for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond Ampleon' standard warranty and Ampleon' product specifications.

Quick reference data — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

Translations — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

12.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

Any reference or use of any 'NXP' trademark in this document or in or on the surface of Ampleon products does not result in any claim, liability or entitlement vis-à-vis the owner of this trademark. Ampleon is no longer part of the NXP group of companies and any reference to or use of the 'NXP' trademarks will be replaced by reference to or use of Ampleon's own Any reference or use of any 'NXP' trademark in this document or in or on the surface of Ampleon products does not result in any claim, liability or entitlement vis-à-vis the owner of this trademark. Ampleon is no longer part of the NXP group of companies and any reference to or use of the 'NXP' trademarks will be replaced by reference to or use of Ampleon's own trademarks.

13. Contact information

For more information, please visit: http://www.ampleon.com

For sales office addresses, please visit: http://www.ampleon.com/sales

AMPLEON

BLF6G22(LS)-180PN

Power LDMOS transistor

14. Contents

1	Product profile
1.1	General description
1.2	Features and benefits
1.3	Applications
2	Pinning information 2
3	Ordering information
4	Limiting values 3
5	Thermal characteristics 3
6	Characteristics 3
7	Application information 4
7.1	Ruggedness in class-AB operation 4
8	Test information 7
9	Package outline
10	Abbreviations11
11	Revision history
12	Legal information
12.1	Data sheet status
12.2	Definitions
12.3	Disclaimers
12.4	Trademarks
13	Contact information
11	Contents

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.